



CBM-40

Mosaic Array Series

Ultraviolet Chip On Board LEDs

Table of Contents

Technology Overview2
Ordering Information3
Binning Structure4
Ordering Bin Kits 5
Optical & Electrical Characteristics6
Typical Spectrum8
Angular Distribution8
Thermal Resistance9
Electrical Pinout9
Mechanical Dimensions Square Package 10
Shipping Tray 11
Packaging Specifications . 12
Revision History 13

Features:

- Mosaic Array UV LED chipset with surface emitting area of 4 mm², 1:1 aspect ratio
- All the benefits of chip on board processing without the need for complicated assembly process
- Vertical chip UV LED technology for high power density and uniform emission
- High thermal conductivity copper coreboard package
- Low-profile window for efficient coupling into small-etendue systems
- Can be operated at variable drive currents up to 6A
- NIST traceable optical and electrical measurement testing
- Environmentally friendly: RoHS and Halogen compliant

Applications:

- Rapid Prototyping and 3D printing
- Machine Vision
- Fiber-coupled illumination
- Specialty Projection Systems for Maskless Lithography
- Medical and Scientific Instrumentation





Technology Overview

Luminus LEDs benefit from innovations in device technology, chip packaging and thermal management. This suite of technologies give engineers and system designers the freedom to develop solutions both high in power and efficiency.

Luminus Mosaic Array LED Technology

Luminus' Devices vertical chip technology enables LED chips with uniform brightness over the entire chip surface. The optical power and brightness produced by these densely packed arrays of devices enable solutions not possible with single chip packages that be used to replace arc and halogen lamps.

Packaging Technology

Thermal management is critical in high power LED applications. With a thermal resistance from junction to heat sink of 0.6 °C/W, Luminus CBM-40 LEDs have the lowest thermal resistance of any UV LED on the market. This will allow the LEDs to be driven at higher current densities while maintaining a low junction temperature, thereby resulting in brighter solutions and longer lifetimes.

Reliability

With designs based on years of chip and packaging development experience, Luminus LEDs are one of the most reliable light sources in the world today. Luminus LEDs pass a rigorous suite of environmental and mechanical stress tests, including mechanical shock, vibration, temperature cycling and humidity, and have been fully qualified for use in extreme high power and high current applications. With very low failure rates and median lifetimes that can exceed 30,000 hours, Luminus UV LEDs are ready for even the most demanding applications.

Environmental Benefits

Luminus LEDs help reduce power consumption and the amount of hazardous waste entering the environment. All LED products manufactured by Luminus are RoHS and Halogen compliant and free of hazardous materials, including lead and mercury.

Understanding Mosaic Array UV LED Test Specifications

Every Luminus LED is fully tested to ensure that it meets the high quality standards expected from Luminus' products.

Testing Temperature

2

Luminus core board products are typically measured in such a way that the characteristics reported agree with how the devices will actually perform when incorporated into a system. This measurement is accomplished by mounting the devices on a 40°C heat sink and measuring the device while fully powered.

This method of measurement ensures that Luminus LEDs perform in the field just as they are specified.

Multiple Operating Points

The tables on the following pages provide typical optical and electrical characteristics for the standard drive conditions. Since the LEDs can be operated over a wide range of drive conditions(currents from 200 mA to 6 A, and duty cycle from <1% to 100%) there are many other potential values attainable. Driving devices beyond recommended driving conditions shortens lifetime.



Ordering Information

Products	Ordering Part Number	Description
CBM-40-UV	CBM-40-UV-C32-FF###-2#	CBM-40 Mosaic Array UV chipset consisting of 4x1mm2 UV LEDs, a thermistor, connectors, and a square copper-core PCB.

Part Number Nomenclature

СВМ — 4	40 —	сс —	C##		FF###-2#
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Product Family	Chip Area	Color	Package Configuration	Bin Kit ^{1,2}
CBM: Copper- core PCB, Mosiac Array	40: 4 mm²	UV = Ultraviolet	C32: 26.5 mm x 16.0 mm	See page 5 for complete bin definition table

Note 1: A Bin Kit represents a group of individual flux or power bins that are shippable for a given ordering part number. Individual flux bins are not orderable.

Note 2: Flux Bin listed is minimum bin shipped - higher bins may be included at Luminus' discretion



CBM-40-UV Binning Structure

CBM-40-UV LEDs are specified for luminous flux and chromaticity/wavelength at a drive current of 3 A (750 mA/mm2) and placed into one of the following Power Bins and Wavelength Bins:

Power Bins³

Color	Power Flux Bin (FF)	Minimum Flux (W)	Maximum Flux (W)
	BC	2.7	3.0
	CA	3.0	3.3
UV	СВ	3.3	3.7
υv	CC	3.7	4.0
	DA	4.0	4.3
	DB	4.3	4.7

Note 3: Luminus maintains a +/- 6% tolerance on power measurements.

Peak Wavelength Bins

Color	Wavelength Bin (###)	Minimum Wavelength (nm)	Maximum Wavelength (nm)
	365	365	370
UV	370	370	375
	385	385	390
	390	390	395



CBM-40 UV Mosaic Array Bin Kits

	Luminous Flux			Ordering
Wavelength Range	Bin Kit Flux Code	Min. Flux	Wavelength Bins	Bin Kit Number
265 275	BC	2.7	365	BC365-21
365-375		2.7	365, 370	BC365-22
	CC	3.7	385, 390	CC385-22
385-395			385	DA385-21
	DA	4.0	390	DA390-21
				385, 390



Reference Optical & Electrical Characteristics ($T_{hs} = 40^{\circ}$ C)^{4,5}

UV					
Parameter	Symbol	Valu	ues ⁶		Unit
Peak Wavelength Range	λ	365 - 375 385-395		nm	
Drive Conditions ⁷	1	3.0	3	.0	A
Peak Wavelength Typ.	λ_p	368	387	392	nm
Current Density	j	0.75	0.	75	A/mm ²
	V _{F min}	3.0	3	.0	V
Forward Voltage	V _F	3.7	3.6		V
	V _{F max}	4.0	4	.0	V
Radiometric Flux ⁸	$\Phi_{_{typ}}$	2.8	4	.1	W
FWHM at 50% of Φ	Δλ _{1/2}	14	14		nm

Parameter	Symbol	Values	Unit
Absolute Minimum Current (CW or Pulsed) ⁹		0.2	А
Absolute Maximum Current (CW) ¹⁰		6	A
Absolute Maximum Surge Current ¹⁰ (Frequency > 240 Hz, duty cycle =10%, t=1ms)		8	A
Maximum Junction Temperature ¹¹	T _{jmax}	100	°C
Storage Temperature Range		-40 to +100	°C
Emitting Area		4.4	mm ²
Emitting Area Dimensions		2.2 x 2.2	mm × mm

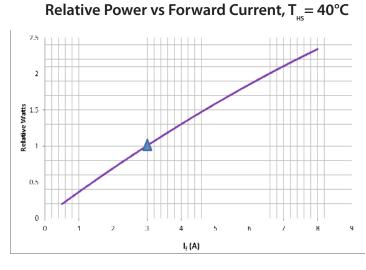
Note 4: Data verified using NIST traceable calibration standard.

Note 5: All data are based on test conditions with a constant heat sink temperature $T_{hs} = 40^{\circ}$ C under pulse testing conditions. Pulse conditions: 25% duty-cycle, frequency of 720Hz, 3 second soak.

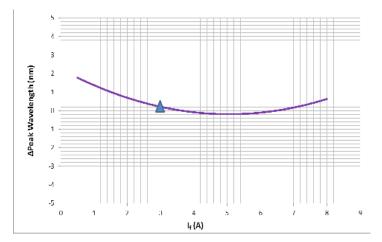
- Note 6: Unless otherwise noted, values listed are typical. Devices are production tested and specified at 3 A.
- Note 7: Listed drive conditions are typical for common applications. CBM40-UV devices can be driven at CW currents ranging from 200 mA to 6 A and at duty cycles ranging from 1% to 100%. Drive current and duty cycle should be adjusted as necessary to maintain the junction temperature desired to meet application lifetime requirements.
- Note 8: Typical total flux from emitting area at listed peak wavelength. Reported performance is included to show trends for a selected power level. For specific minimum and maximum values, use bin tables. For product roadmap and future performance of devices, contact Luminus.
- Note 9: Special design considerations must be observed for operation under 1 A. Please contact Luminus for further information.
- Note 10: CBM-40-UV LEDs are designed for operation to an absolute maximum current as specified above. Product lifetime data is specified at recommended forward drive currents. Sustained operation at or beyond absolute maximum currents will result in a reduction of device life time compared to recommended forward drive currents. Actual device lifetimes will also depend on junction temperature. Refer to the lifetime derating curves for further information. In pulsed operation, rise time from 10-90% of forward current should be longer than 0.5 µseconds.
- Note 11: Lifetime dependent on LED junction temperature. Input power and thermal system must be properly managed to ensure lifetime.



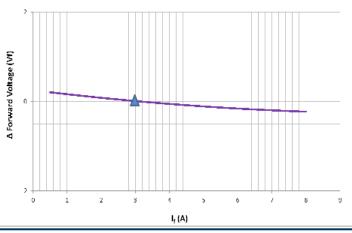
Optical & Electrical Characteristics



Peak Wavelength vs Forward Current



Forward Voltage vs Forward Current

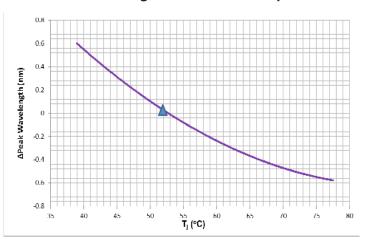


0.02 0.06 0.05

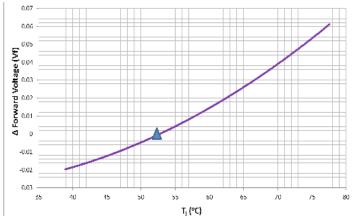
1.1 1.08 1.05 1.04 Relative Watts 1 0.98 0.96 0.94 0.92 0.9 35 45 65 40 50 55 60 70 75 80 Tj (°C)

Relative Power vs Junc. Temperature

Peak Wavelength vs Junction Temperature



Forward Voltage vs Junction Temperature

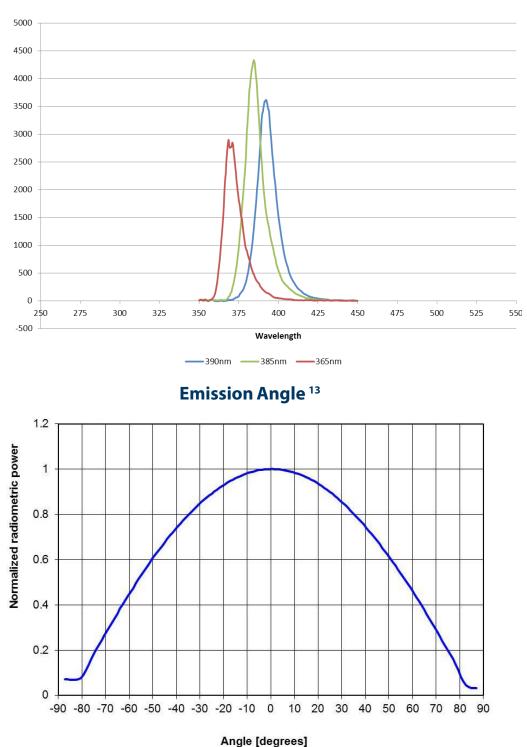


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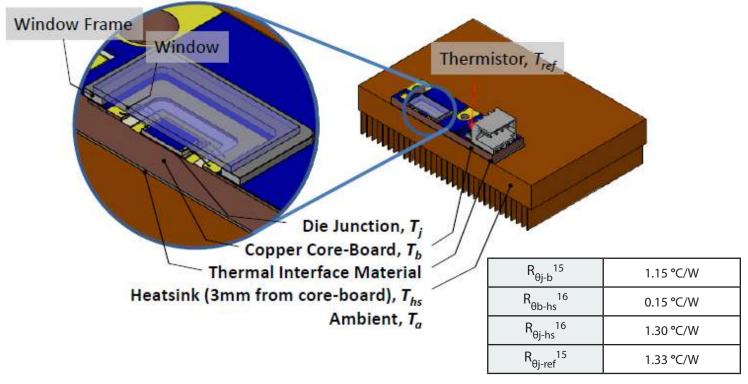


Note 12: Typical spectrum at current of 9 A in continuous operation.

Note 13: Detailed information on emission including ray trace files can be found at: http://www.luminus.com/resource/design.html



Thermal Resistance CBM-40-UV



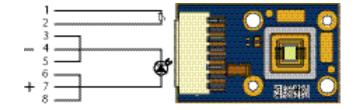
- Note 14: Real thermal resistance data "Electrical" thermal resistance values available upon request
- Note 15: Thermal resistance values are based on measured wavelength shift data.
- Note 16: Thermal Resistance is based on eGraf 1205 Thermal interface.

Thermistor Information

The thermistor used in CBT-39 devices are mounted on coreboards is from Murata Manufacturing Co. The global part number is NCP18XH103J03RB. Please see http://www.murata.com/ for details on calculating thermistor temperature.

For more information on use of the thermistor, please contact Luminus directly.

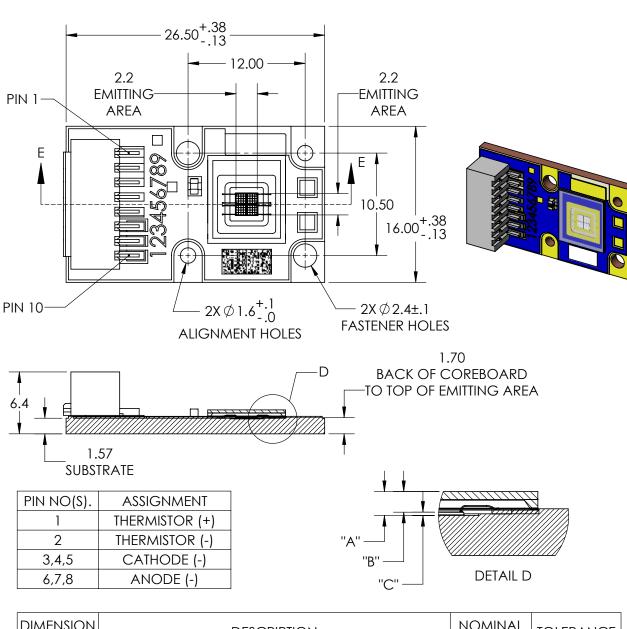
Electrical Pinout





DIMENSIONS IN MILLIMETERS

Mechanical Dimensions – CBM-40-UV-C32 Mosaic Array LED Emitter



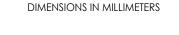
DIMENSION NAME	DESCRIPTION	NOMINAL DIMENSION	TOLERANCE
"A"	TOP OF METAL SUBSTRATE TO TOP OF WINDOW	.91	±.13
"B"	TOP OF EMITTING AREA TO TOP OF WINDOW	.79	±.11
"C"	TOP OF METAL SUBSTRATE TO TOP OF EMITTING AREA	.13	±.02

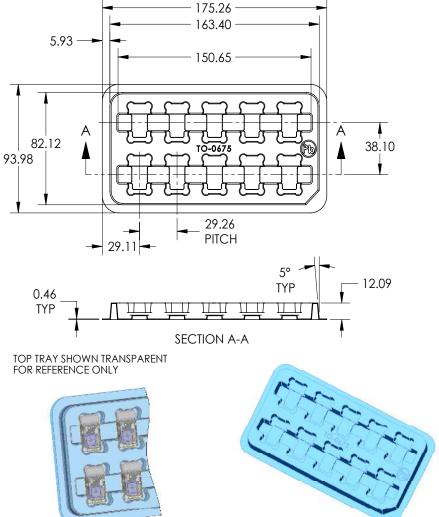
DWG-002661

• Connector- MOLEX Part Number: 874380843 or Global Part Number: WTB16-081SF.



Shipping Tray Outline - CBM-40







Packing and Shipping Specification (CBM-40)

Packing Specification

Packing Configuration	Qty /Pack	Box Dimensions (diameter x W, mm)	Gross Weight (kg)
Stack of 5 trays with 10 devices per tray Each pack is enclosed in ESD bag	50	95 x 176 x 50	0.45

Product Label Specification

Label Fields (subject to change):

- 6-8 digit Box number (for Luminus internal use)
- Luminus ordering part number
- Quantity of devices in pack
- Part number revision (for Luminus internal use)
- Customer's part number (optional)
- Flux Bin
- 2D Bar code



Shipping Box

Shipping Box	Quantity	Material	Dimensions (L x W x H, mm)
Carton Box	1 -20 packs	S4651	560 x 560 x 200



History of Changes

Rev	Date	Description of Change
А	08/07/2015	Preliminary Specifications for 365nm and 385nm CBM-40 Parts
01	10/05/2015	Initial Release
02	03/28/2016	Updated binning information



A CAUTION UV radiation hazard. Use only with shielding in place. Protect eyes & skin from exposure to UV light.

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